ELEC 312: ELECTRONICS – II : ASSIGNMENT-4 (Hint/Sol) Department of Electrical and Computer Engineering Fall – 2012

Q.1: Show the design of a class-A power amplifier using BJT devices, employed to deliver 10 W of ac signal power to a load of 10 ohms. Find the V_{CC} required, the I_Q required and design the active circuit to provide the required I_Q . Comment on the heat dissipation limits of the BJT devices used in your design. R

Hints:

The class-A power amplifier using BJT is given below:



 $P_L = (1/2) (V_o^2/R_L), V_o = \sqrt{(2 P_L R_L)}, I_o = V_o/R_L$, for maximum efficiency $V_{CC} = V_o$, And $I_{CQ} = |I_o|$ Now follow the example (Problem 5.1) in ch.5 of my lecture note.

Q.2: Design an idealized class-B output stage as shown in Figure 2, to deliver an average of 25 W to an 8 Ω speaker. The peak output voltage must be no larger than 80% of supply voltages V_{CC}. Determine: (i) the required value of V_{CC}, (ii) the peak current in each transistor, (iii) the average power dissipated in each transistor, and (iv) the power conversion efficiency.



Figure 2: Basic class-B output stage

Hints:

- $P_{\rm L} = (1/2) (V_0^2/R_{\rm L}), V_0 = \sqrt{(2 P_{\rm L} R_{\rm L})} \text{ now, } V_0 < 80\% \text{ of } V_{\rm CC}, \text{ hence}$ (i) $V_{CC} = V_0 / 0.8$
- I_o (peak) = V_o (peak)/ R_L (ii)
- (iii)
- $P_{Qn} (max) = P_{Qp} (max) = V_{CC}^{2} / (\pi^{2}R_{L})$ $\eta = P_{load} / P_{supply} * 100\%, \text{ where } P_{load} = (1/2) (V_{o}^{2}/R_{L}) \text{ and } P_{S+} = P_{S-} =$ (iv) $(1/\pi)(V_o/R_L)V_{CC}, P_{supply} = P_{S^+} + P_{S^-}$

Q.3: Determine the required biasing in a MOSFET class-AB output stage. The circuit is shown in Figure 3. The parameters are $V_{DD} = 10$ V and $R_L = 20 \Omega$. The transistors are matched, and the parameters are K = 0.20 A/V² and $|V_T| = 1$ V. The quiescent drain current is to be 20% of the load current when $v_0 = 5$ V.



Figure 3: MOSFET class-AB output stage

Hints:

For $\overline{v_o} = 5 \text{ V}$, $i_L = v_o/R_L = 5/20 = 0.25$. Then $I_0 = 20\%$ of 0.25 A = 0.05 A.

 $I_{O} = i_{Dn} = i_{Dp}$, when $v_{o} = 0$. Thus $I_{O} = K (V_{BB}/2 - |V_{T}|)^{2}$ calculate $V_{BB}/2$.